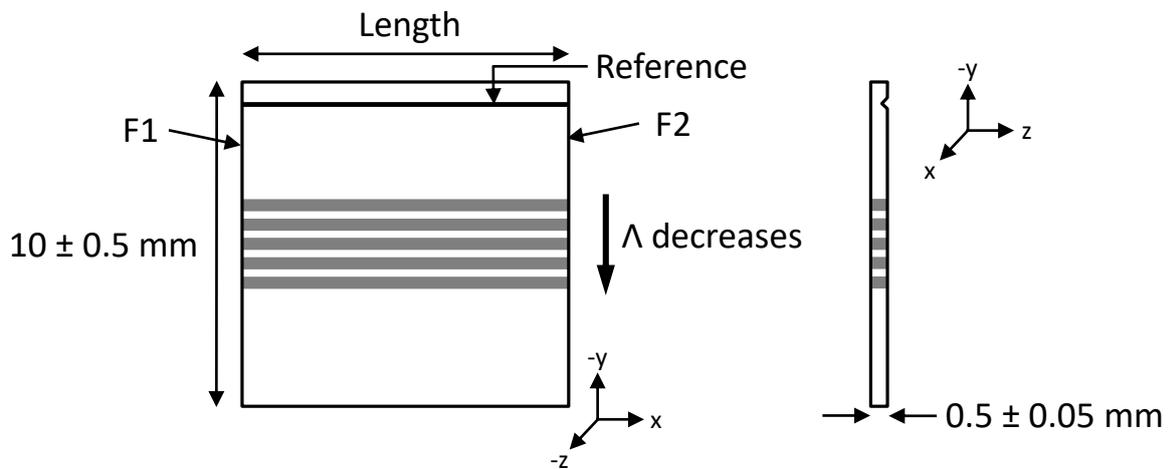


Device Specification

MSHG1230-0.5-xx



[Image for reference only. Not to scale.]

Description MgO doped PPLN SHG crystal for 1220-1255nm generating 610-627nm
Thickness(z) $0.5\text{mm} \pm 0.05\text{mm}$
Width(y) $10\text{mm} \pm 0.5\text{mm}$
Length(x) $20\text{mm} \pm 0.5\text{mm}$, $3\text{mm} \pm 0.1\text{mm}$
Periods(Λ) 10.40, 10.55, 10.70, 10.85, $11.00\mu\text{m}$

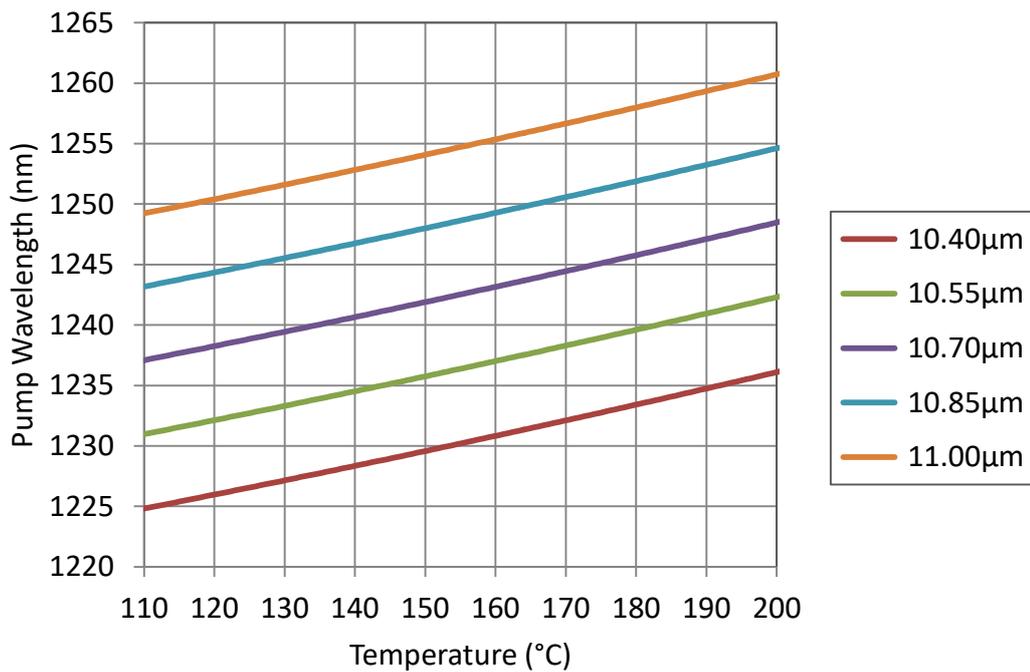
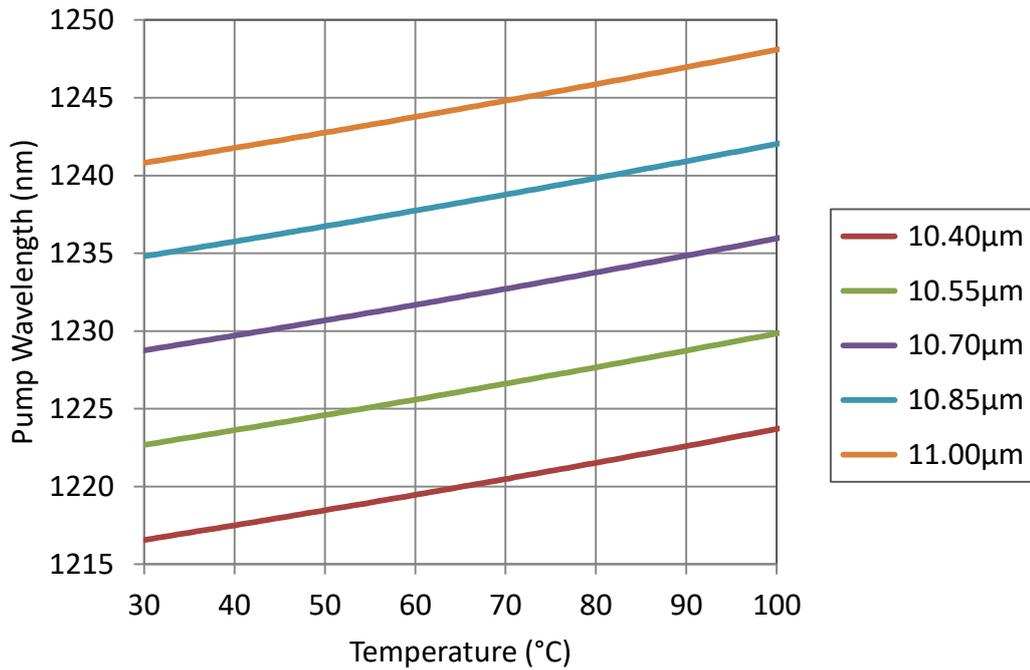
NOTES:

- 1 The SHG device material is Magnesium doped Lithium Niobate with five periodically poled gratings. Each grating is 0.5mm wide with individual periods as listed above. A saw-cut reference mark is provided on the +z face of the crystal to determine the largest grating period (see above diagram). Each poled grating is separated by 0.2mm wide regions of unpoled material.
- 2 The average mark-to-space ratio of each grating is better than 70:30.
- 3 Each device is etched to make the poled gratings visible. Due to the wet-etch nature of this process the top and bottom surface finish of each device may appear cloudy or uneven.
- 4 Perpendicularity of input/output facets F1 and F2 to gratings is within $\pm 0.15^\circ$. Parallelism between end facets F1 and F2 is within ± 5 minutes.
- 5 Optical finish of facets F1 and F2 is within 20/10 scratch dig with $\lambda/4@633\text{nm}$. No more than two $100\mu\text{m}$ size chips per end facet.
- 6 Double band AR coating to $R < 1\% @ 1210-1260\text{nm}$, $R < 1\% @ 600-610\text{nm}$ ($R \sim 3\% @ 630\text{nm}$) on both input/output facets.

Device Specification

MSHG1230-0.5-xx

2.0/2017



Please note these are calculated tuning curves only and actual values may vary.

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